

**A000171(028)**

**B. Tech. (Hon's) (First Semester) Examination,  
Nov.-Dec. 2023**

**(ESE Branch)**

**FOUNDATION of ELECTRONICS ENGINEERING**

***Time Allowed : Three hours***

***Maximum Marks : 100***

***Minimum Pass Marks : 35***

***Note : Attempt all questions. Part (a) from each question is compulsory & carries 4 marks each. Attempt any two parts from (b), (c) and (d) of each question & carries 8 marks each.***

**Unit-I**

1. (a) Explain the significance of the small-signal model of non-linear devices in electronic circuits.

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## [ 2 ]

- (b) Demonstrate about donor and acceptor impurities in semiconductors. How do they affect the conductivity of the material? 8
- (c) Briefly differentiate between metals, semiconductors and insulators based on their electrical properties and energy band structures. 8
- (d) Describe Poisson's equation and its relevance in semiconductor physics. 8

## Unit-II

2. (a) Differentiate between homo-junction and hetero-junction. 4
- (b) Describe the IV characteristics of a diode. What regions are typically observed in these characteristics? 8
- (c) Provide an overview of small-signal models of diodes. How are they useful in circuit analysis? 8
- (d) Briefly explain bridge rectifier. 8

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## [ 3 ]

### Unit-III

3. (a) Explain the structure of BJT. 4
- (b) Draw and label the IV characteristics of a bipolar transistor. Explain the Early effect. 8
- (c) Briefly discuss the Ebers-Moll model for bipolar transistors. 8
- (d) Give difference between BJT and FET. 8

### Unit-IV

4. (a) Describe the features of a JFET. 4
- (b) Why is a field-effect transistor (FET) considered essentially a voltage-controlled device? Explain the role of gate voltage in FET operation. 8
- (c) Define accumulation, depletion, and inversion regions in a MOSFET. 8
- (d) Outline the CV characteristics of a MOSFET? 8

### Unit-V

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5. (a) Highlight advantages and disadvantages of CB configuration.

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(b) Provide a brief explanation of the common-source amplifier configuration and its significance in electronic circuits.

8

(c) Explain the operation of a common collector amplifier with neat circuit diagram.

8

(d) Explain the input and output characteristics of common-emitter configuration of a BJT..

8